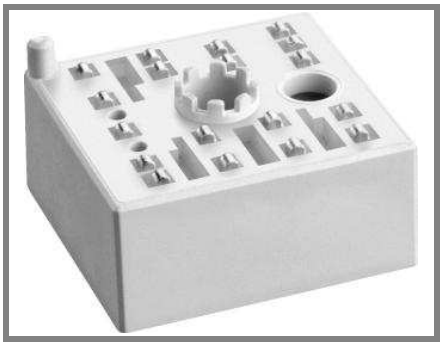
# SKiiP 04AC066V1



**MiniSKiiP® 0**

3-phase bridge inverter

**SKiiP 04AC066V1**

## Features

- Trench IGBT´s
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

## Typical Applications*

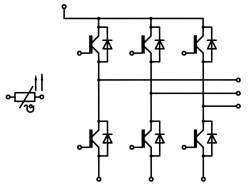
- Inverter up to 6,3 kVA
- Typical motor power 4,0 kW

## Remarks

- Case temperature limited to $T_C$= 125°C max., product reliability results are valid for $T_j$ = 150°C
- SC data: $t_p \leq 6$ s; $V_{GE} \leq 15$ V; $T_j$ = 150°C; $V_{CC}$ = 360 V
- $V_{CEsat}$, $V_F$= chip level value
- Temp.Sensor: No basic insulation to main circuit, max. potential difference 850V to -DC

| **Absolute Maximum Ratings** | $T_S$ = 25 °C, unless otherwise specified | | |
|---|---|---|---|
| **Symbol** | **Conditions** | **Values** | **Units** |
| **IGBT - Inverter** | | | |
| $V_{CES}$ | | 600 | V |
| $I_C$ | $T_s$ = 25 (70) °C ,$T_j$ = 150 °C | 30 (21) | A |
| $I_C$ | $T_s$ = 25 (70) °C ,$T_j$ = 175 °C | 33 (25) | A |
| $I_{CRM}$ | $t_p$ = 1 ms | 40 | A |
| $V_{GES}$ | | ± 20 | V |
| $T_j$ | | -40...+175 | °C |
| **Diode - Inverter** | | | |
| $I_F$ | $T_s$ = 25 (70) °C ,$T_j$ = 150 °C | 24 (16) | A |
| $I_F$ | $T_s$ = 25 (70) °C ,$T_j$ = 175 °C | 31 (23) | A |
| $I_{FRM}$ | $t_p$ = 1 ms | 40 | A |
| $T_j$ | | -40...+175 | °C |
| $I_{tRMS}$ | per power terminal (20 A / spring) | 20 | A |
| $T_{stg}$ | $T_{op} \leq T_{stg}$ | -40...+125 | °C |
| $V_{isol}$ | AC, 1 min. | 2500 | V |

| **Characteristics** | $T_S$ = 25 °C, unless otherwise specified | | | | |
|---|---|---|---|---|---|
| **Symbol** | **Conditions** | **min.** | **typ.** | **max.** | **Units** |
| **IGBT - Inverter** | | | | | |
| $V_{CEsat}$ | $I_{Cnom}$ = 20 A ,$T_j$ = 25 (150) °C | 1,1 | 1,45 (1,65) | 1,85 (2,05) | V |
| $V_{GE(th)}$ | $V_{GE}$ = $V_{CE}$, $I_C$ = 1 mA | | 5,8 | | V |
| $V_{CE(TO)}$ | $T_j$ = 25 (150) °C | | 0,9 (0,85) | 1 (0,9) | V |
| $r_T$ | $T_j$ = 25 (150) °C | | 30 (42,5) | 45 (60) | mΩ |
| $C_{ies}$ | $V_{CE}$ = 25 V, $V_{GE}$ = 0 V, f = 1 MHz | | 1,13 | | nF |
| $C_{oes}$ | $V_{CE}$ = 25 V, $V_{GE}$ = 0 V, f = 1 MHz | | 0,25 | | nF |
| $C_{res}$ | $V_{CE}$ = 25 V, $V_{GE}$ = 0 V, f = 1 MHz | | 0,18 | | nF |
| $R_{CC'+EE'}$ | spring contact-chip $T_s$ = 25 (150 )°C | | | | mΩ |
| $R_{th(j-s)}$ | per IGBT | | 1,6 | | K/W |
| $t_{d(on)}$ | under following conditions | | 15 | | ns |
| $t_r$ | $V_{CC}$ = 300 V, $V_{GE}$ = ± 15V | | 30 | | ns |
| $t_{d(off)}$ | $I_{Cnom}$ = 20 A, $T_j$ = 150 °C | | 175 | | ns |
| $t_f$ | $R_{Gon}$ = $R_{Goff}$ = 15 Ω | | 45 | | ns |
| $E_{on}$($E_{off}$) | inductive load | | 0,8 (0,7) | | mJ |
| **Diode - Inverter** | | | | | |
| $V_F$ = $V_{EC}$ | $I_{Fnom}$ = 20 A ,$T_j$ = 25 (150) °C | | 1,6 (1,65) | 1,9 (1,95) | V |
| $V_{(TO)}$ | $T_j$ = 25 (150) °C | | 1 (0,9) | 1,1 (1) | V |
| $r_T$ | $T_j$ = 25 (150) °C | | 30 (37,5) | 40 (47,5) | mΩ |
| $R_{th(j-s)}$ | per diode | | 2,5 | | K/W |
| $I_{RRM}$ | under following conditions | | 27 | | A |
| $Q_{rr}$ | $I_{Fnom}$ = 20 A, $V_R$ = 300 V | | 2,25 | | C |
| $E_{rr}$ | $V_{GE}$ = 0 V, $T_j$ = 150 °C | | 0,55 | | mJ |
| | $di_F/dt$ = 1280 A/ s | | | | |
| **Temperature Sensor** | | | | | |
| $R_{ts}$ | 3 %, $T_r$ = 25 (100) °C | | 1000(1670) | | Ω |
| **Mechanical Data** | | | | | |
| m | | | 21,5 | | g |
| $M_s$ | Mounting torque | 2 | | 2,5 | Nm |



**AC**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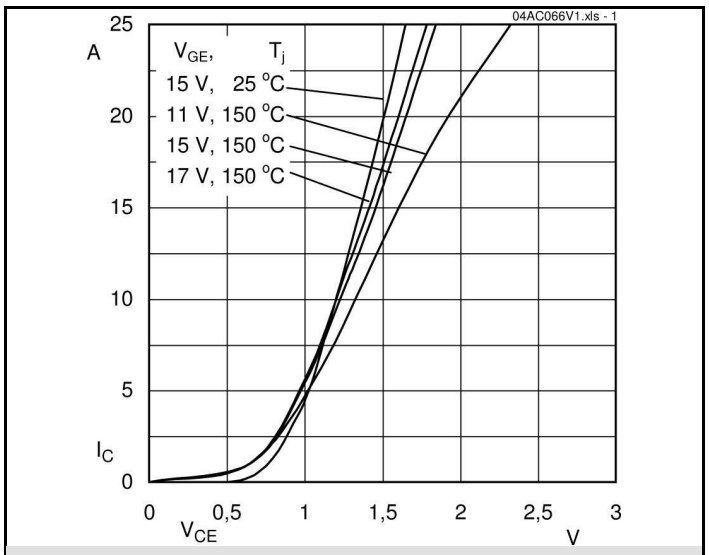


Fig. 1 Output characteristic

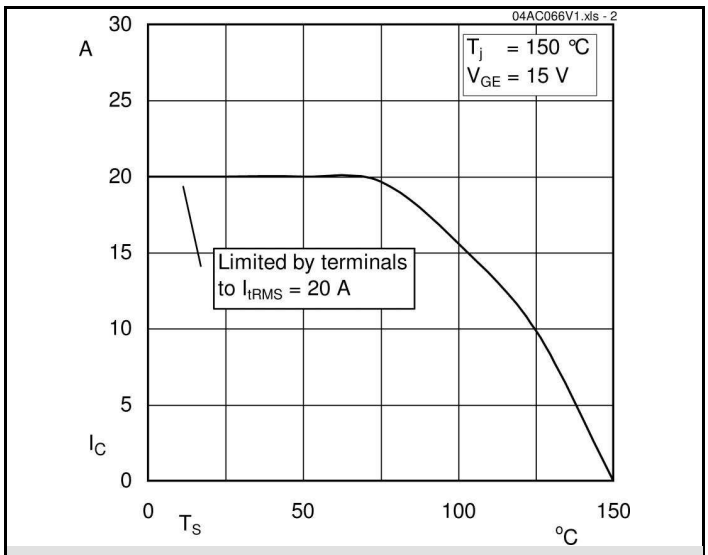


Fig. 2 Rated current vs. temperature

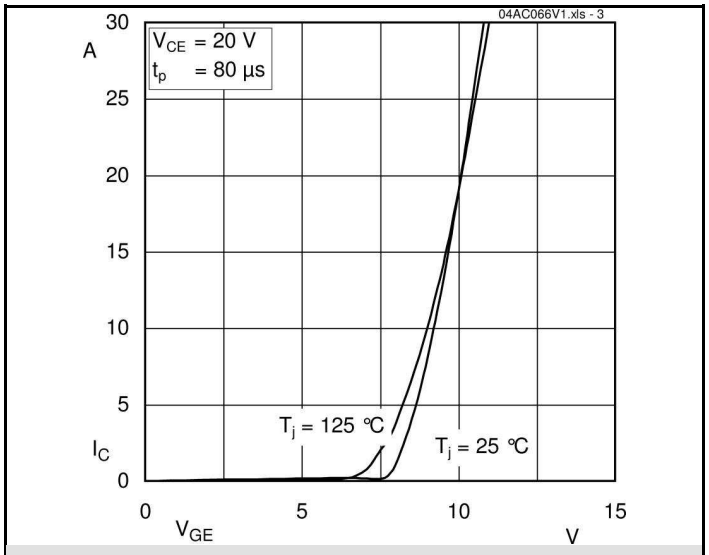


Fig. 3 Typ. transfer characteristic

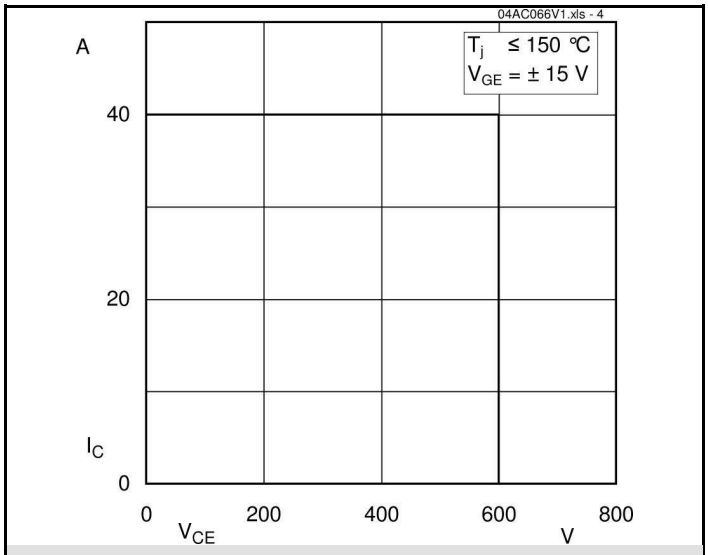


Fig. 4 Reverse bias safe operating area

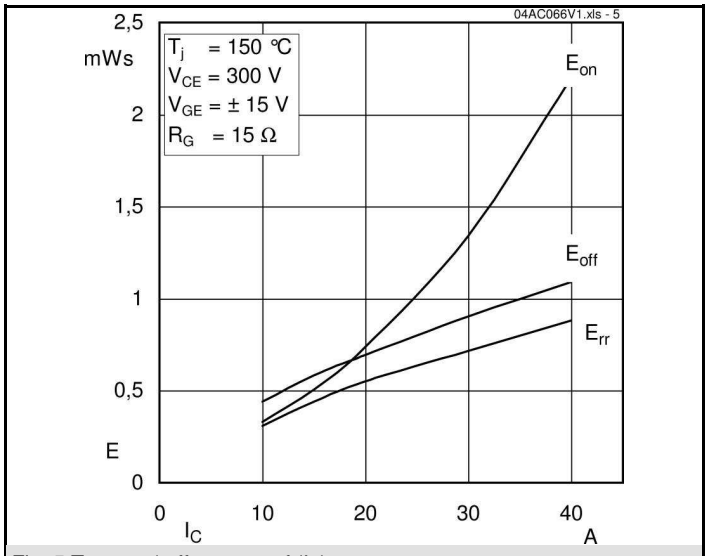


Fig. 5 Turn-on /-off energy = f ($I_C$)

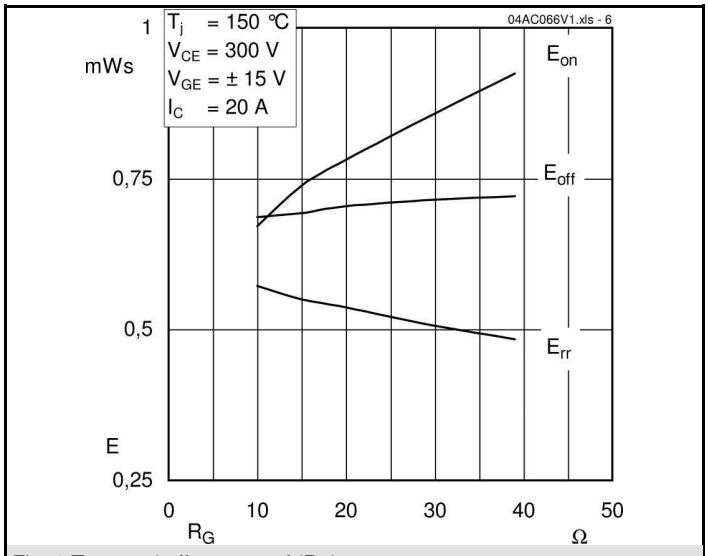


Fig. 6 Turn-on /-off energy = f ($R_G$)

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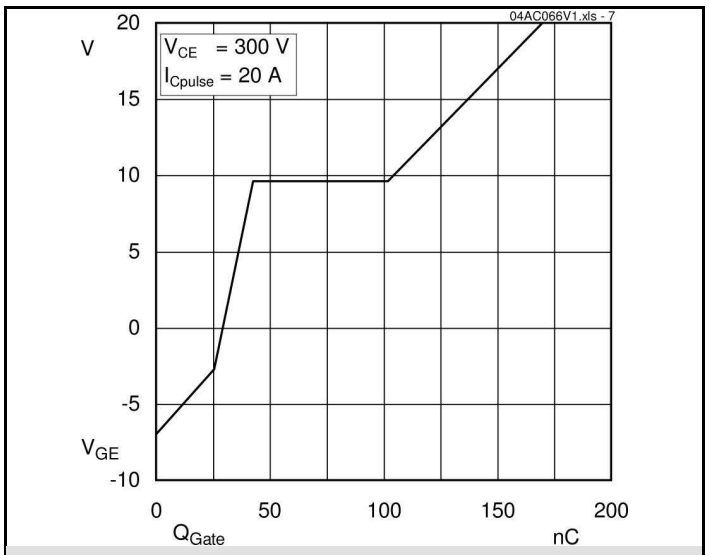


Fig. 7 Typ. Gate charge characteristic

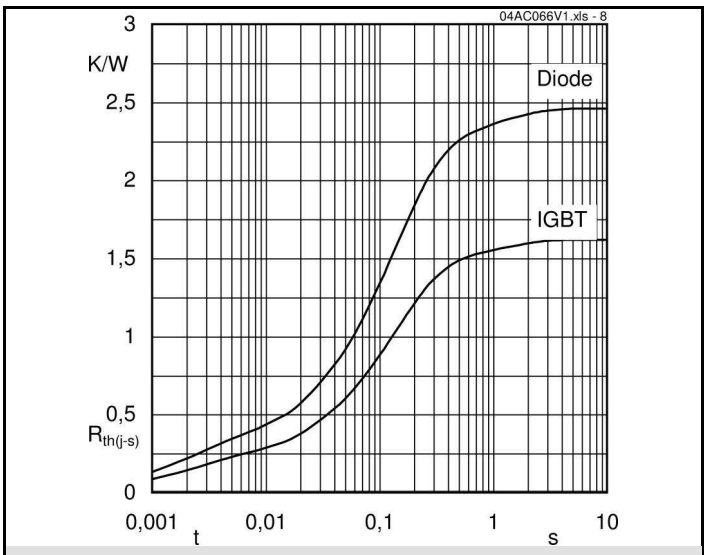


Fig. 8 Thermal impedance

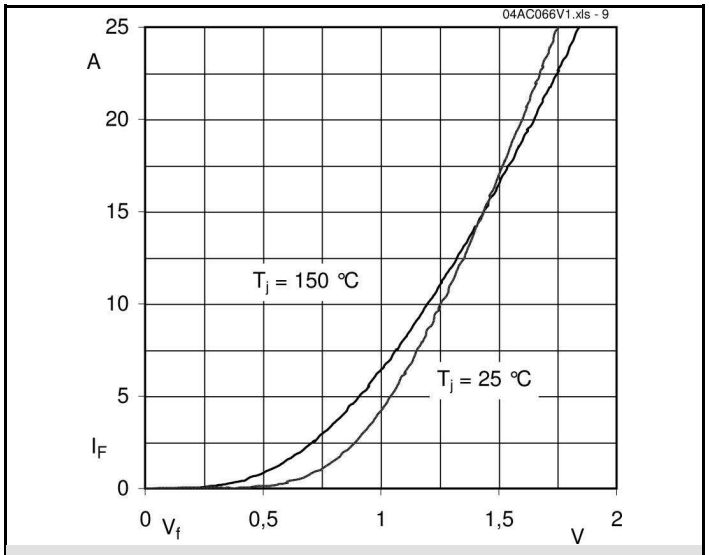


Fig. 9 Freewheeling diode forward characteristic

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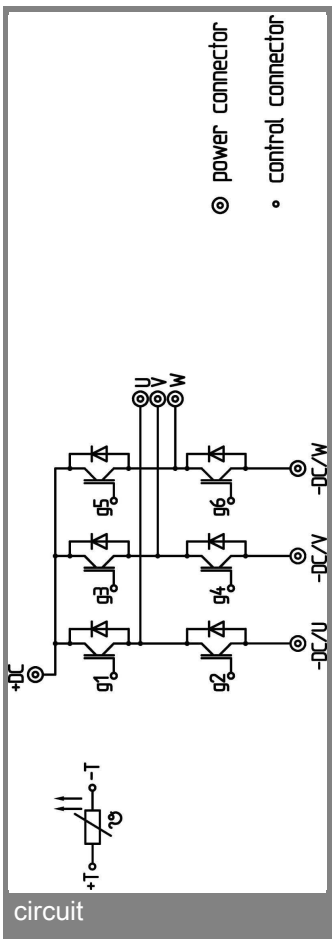
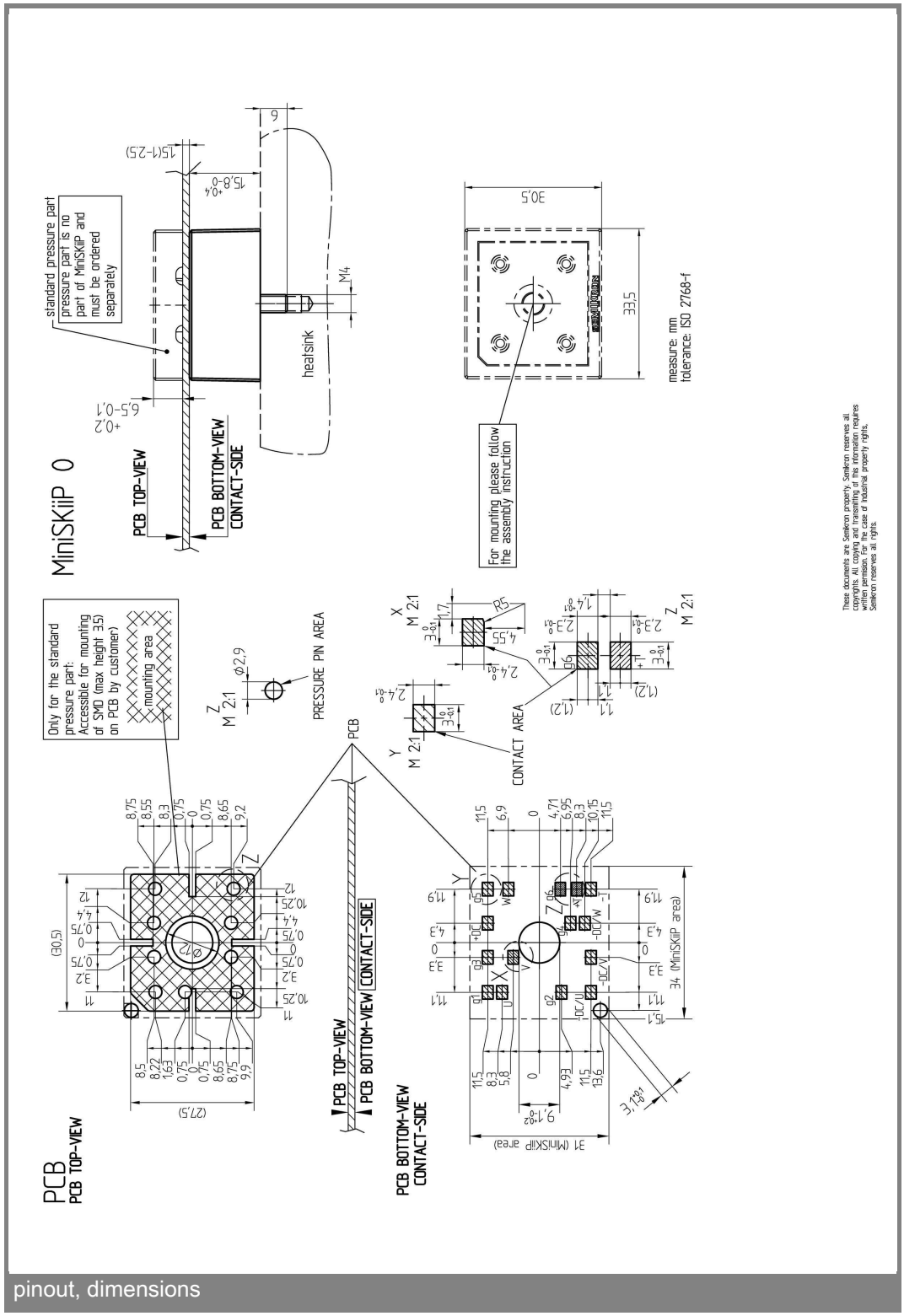



circuit




pinout, dimensions

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

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